# Medium power transistor (30V, 2A) 2SC5916

#### ● Features

- 1) High speed switching. (Tf: Typ.: 20ns at Ic = 2A)
- 2) Low saturation voltage, typically

(Typ.: 200mV at Ic = 1.0A, IB = 0.1A)

- 3) Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SA2113

# Applications

Low frequency amplifier High speed switching

#### ●Structure

NPN Silicon epitaxial planar transistor

## Packaging specifications

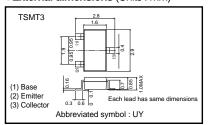
Туре	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	3000
2SC5916		0

# ● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	30	V
Collector-emitter voltage	Vceo	30	V
Emitter-base voltage	VEBO	6	V
Collector current	lc	2	Α
Collector current	ICP	4	A *1
Power dissipation	Pc	500	mW *2
Junction temperature	Tj	150	°C
Range of storage temperature	Tstg	-55~+150	°C

<sup>\*1</sup> Pw=10ms

## ●External dimensions (Units : mm)



 $<sup>\</sup>ast 2$  Each terminal mounted on a recommended land.

## ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	BVceo	30	-	-	V	Ic=100μA
Collector-emitter breakdown voltage	ВУсво	30	-	-	V	Ic=1mA
Emitter-base breakdown voltage	ВУево	6	-	-	V	IE=100μA
Collector cut-off current	Ісво	-	-	1.0	μΑ	Vcb=20V
Emitter cut-off current	ІЕВО	_	-	1.0	μΑ	V <sub>EB</sub> =4V
Collector-emitter staturation voltage	VCE(sat)	-	200	400	mV	Ic=1.0A, Iв=0.1A
DC current gain	hfe	120	-	390	_	VcD=2V, Ic=100mA
Transition frequency	fT	-	250	-	MHz	Vc=10V, I=-100mA, f=10MHz
Collector output capacitance	Cob	_	15	-	pF	VcB=10V, IE=0, f=1MHz
Turn-on time	Ton	_	25	_	ns	Ic=2A I <sub>B1</sub> =200mA I <sub>B2</sub> =−200mA Vcc ≒−25V
Storage time	Tstg	_	100	-	ns	
Fall time	Tf	_	20	-	ns	

## ●hFE RANK

Q	R		
120-270	180-390		

### ●Electrical characteristic curves

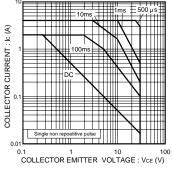


Fig.1 Safe operating area

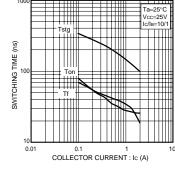


Fig.2 Switching Time

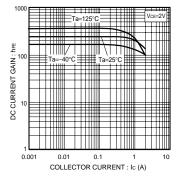


Fig.3 DC current gain vs. collector

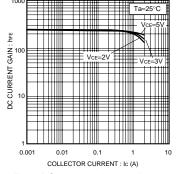
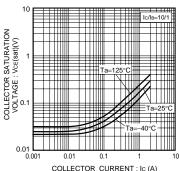


Fig.4 DC current gain vs. collector



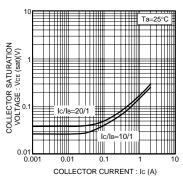


Fig.5 Collector-emitter saturation voltage Fig.6 Collector-emitter saturation voltage vs. collector current vs. collector current

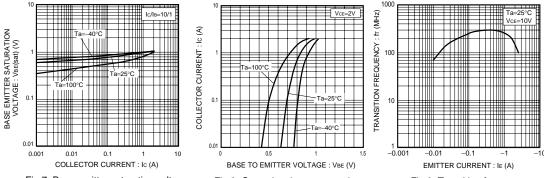


Fig.7 Base-emitter saturation voltage vs. collector current

Fig.8 Ground emitter propagation characteristics

Fig.9 Transition frequency

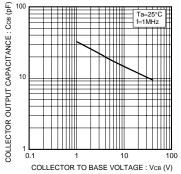
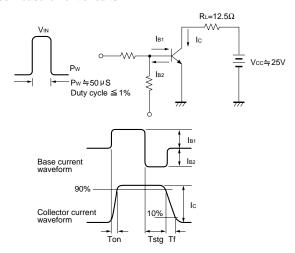


Fig.10 Collector output capacitance

## •Switching characteristics measurement circuits



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Appendix1-Rev1.0